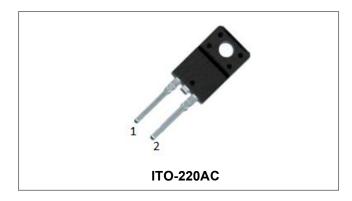






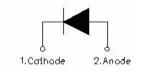
# **SDURF860 ULTRAFAST RECTIFIER**



# **Applications**

- Antiparallel diode for high frequency switching devices
- Anti saturation diode
- Snubber diode
- Free wheeling diode in converters and motor control circuits
- Rectifiers in switch mode power supplies (SMPS)
- · Inductive heating and melting
- Uninterruptible power supplies (UPS)
- Ultrasonic cleaners and welders

# **Circuit Diagram**



### **Features**

- Ultra-Fast switching
- High current capability
- Low reverse leakage current
- High surge current capability
- This is a Pb free device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

## **Maximum Ratings:**

| Characteristics  | Symbol   | Condition                                       | Max.                                  | Units |
|--|--|---|---------------------------------------|-------|
| Peak Repetitive Reverse Voltage<br>Working Peak Reverse Voltage<br>DC Blocking Voltage | $egin{array}{c} V_{RRM} \ V_{RWM} \end{array}$ | -   | 600                                   | V     |
| Average Rectified Forward Current  | I <sub>F (AV)</sub>                            | 50% duty cycle @Tc=100°C, rectangular wave form | , , , , , , , , , , , , , , , , , , , |       |
| Peak One Cycle Non-Repetitive Surge<br>Current   | I <sub>FSM</sub>                               | 8.3ms, Half Sine pulse                          | 110                                   | А     |

## **Electrical Characteristics:**

| Characteristics       | Symbol          | Condition   | Тур. | Max. | Units |
|-----------------------|-----------------|---|------|------|-------|
| Forward Voltage Drop* | V <sub>F1</sub> | @8A, Pulse, T <sub>J</sub> = 25°C                                   | 1.3  | 1.7  | V     |
| Reverse Current*      | I <sub>R1</sub> | @V <sub>R</sub> = rated V <sub>R</sub> , T <sub>J</sub> = 25°C      | 0.3  | 5    | μA    |
|                       | $I_{R2}$        | @V <sub>R</sub> = rated V <sub>R</sub> , T <sub>J</sub> = 125°C     | 84   | 500  | μΑ    |
| Reverse Recovery Time | t <sub>rr</sub> | I <sub>F</sub> =500mA, I <sub>R</sub> =1A,and I <sub>m</sub> =250mA | 42   | 50   | ns    |

<sup>\*</sup> Pulse width < 300 µs, duty cycle < 2%

- China Germany Korea Singapore United States
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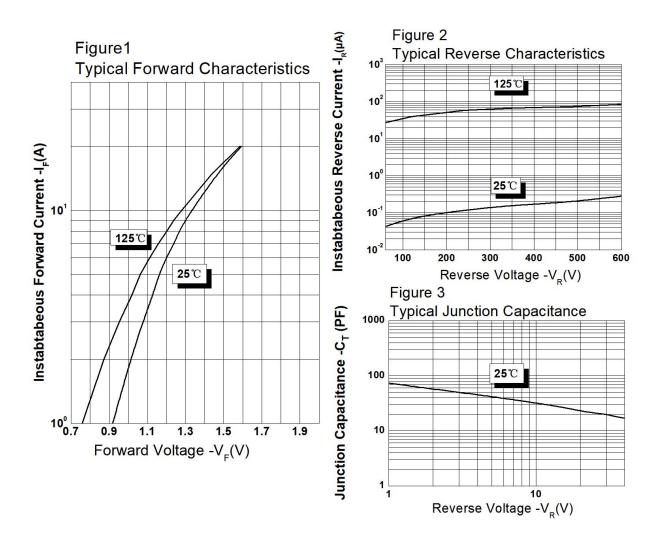




# **Thermal-Mechanical Specifications:**

| Characteristics                                | Symbol            | Condition    | Specification | Units |
|--|-------------------|--------------|---------------|-------|
| Junction Temperature                           | TJ                | -            | -55 to +150   | °C    |
| Storage Temperature                            | T <sub>stg</sub>  | -            | -55 to +150   | °C    |
| Typical Thermal Resistance Junction to Ambient | R <sub>θ</sub> JA | DC operation | 25            | °C/W  |
| Approximate Weight                             | wt                | -            | 1.65          | g     |
| Case Style                                     | ITO-220AC         |              |               |       |

## **Ratings and Characteristics Curves**



<sup>•</sup> China - Germany - Korea - Singapore - United States •

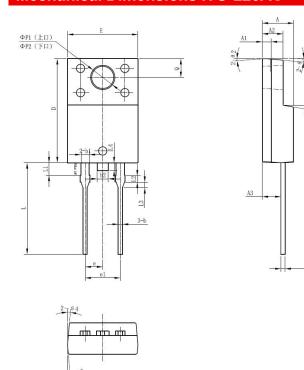
<sup>•</sup> http://www.smc-diodes.com - sales@ smc-diodes.com •





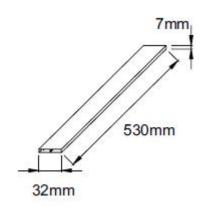


## **Mechanical Dimensions ITO-220AC**



| SYMBOL          | Millimeters |       |       |  |  |
|-----------------|-------------|-------|-------|--|--|
| STIVIBUL        | MIN.        | TYP.  | MAX.  |  |  |
| Α               | 4.30        | 4.50  | 4.70  |  |  |
| A1              | 1.10        | 1.30  | 1.50  |  |  |
| A2              | 2.80        | 3.00  | 3.20  |  |  |
| A3              | 2.50        | 2.70  | 2.90  |  |  |
| b               | 0.50        | 0.60  | 0.75  |  |  |
| b1              | 1.10        | 1.20  | 1.35  |  |  |
| b2              | 1.50        | 1.60  | 1.75  |  |  |
| С               | 0.55        | 0.60  | 0.75  |  |  |
| D               | 14.80       | 15.00 | 15.20 |  |  |
| E               | 9.96        | 10.16 | 10.36 |  |  |
| е               | -           | 2.55  | -     |  |  |
| e1              | _           | 5.10  | -     |  |  |
| H1              | 6.50        | 6.70  | 6.90  |  |  |
| L               | 12.70       | 13.20 | 13.70 |  |  |
| L1              | 1.60        | 1.80  | 2.00  |  |  |
| L2              | 0.80        | 1.00  | 1.20  |  |  |
| L3              | 0.60        | 0.80  | 1.00  |  |  |
| L4              | _           | 1.10  | 1.50  |  |  |
| ΦP1(上□)         | 3.30        | 3.50  | 3.70  |  |  |
| <b>ΦP2</b> (下口) | 2.99        | 3.19  | 3.39  |  |  |
| Q               | 2.50        | 2.70  | 2.90  |  |  |
| Θ1              |             | 5°    |       |  |  |
| Θ2              |             | 4°    |       |  |  |
| Θ3              |             | 10°   |       |  |  |
| Θ4              |             | 5°    |       |  |  |
| Θ5              |             | 5°    |       |  |  |

## **Tube Specification**



# **Marking Diagram**



Where XXXXX is YYWWL

SDUR = Device Type
F = Package type
8 = Forward Current (8A)
60 = Reverse Voltage (600V)
SSG = SSG

SSG = SSG YY = Year WW = Week L = Lot Number

**Cautions:** Molding resin Epoxy resin UL:94V-0

# **Ordering Information:**

| Device   | Package             | Shipping     |  |
|----------|---------------------|--------------|--|
| SDURF860 | ITO-220AC (Pb-Free) | 50 pcs/ tube |  |

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

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